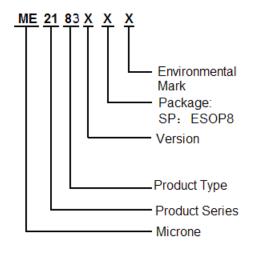


# 2A,1.0MHZ Synchronous Step-Up DC/DC Converter

### **General Description**

The ME2183 is synchronous, 2A, 1.0MHZ step-up DC-DC Converter, which mainly consists of a reference voltage source, an oscillation circuit, an error amplifier, a phase compensation circuit, a PWM / PFM switching control circuit and an adjustable output current limit circuit. With an internal low-ON-resistance N-ch Power MOS and P-ch Power MOS. This product is ideal for applications requiring high efficiency and a high output current.

### **Selection Guide**



### Features

- •High efficiency.( up to 93%)
- •Up to 90% Efficiency at  $I_{OUT}$ =2A  $V_{OUT}$  = 5V from 3.3V Input.
- •Guaranteed 2.5A Output Current at  $V_{OUT} = 5V$  from 3.3V Input
- •Synchronous and internal P-ch Power MOSFET and N-ch power MOSFET ,No Schottky Diode Required
- •Oscillator frequency: 1.0MHz
- •Reference voltage : 1.25V (±2%)
- Input voltage range: 2.3 V to 5.5 V
- Continuous output current: 2.0A typ.

(V<sub>IN</sub>=3V, V<sub>OUT</sub>=5.0V)

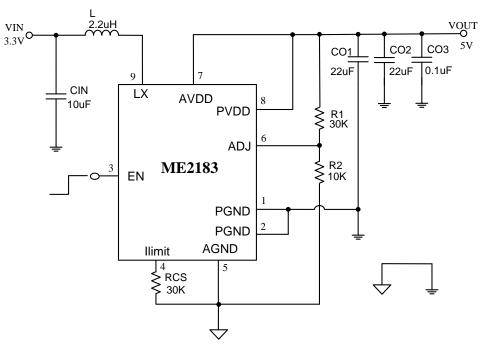
- Soft start function
- •Shutdown function:1.0µA max.
- •UVLO (under-voltage lockout) function
- •Current Limit: adjustable by the Rcs using different valve
- ●Thermal Shutdown Preotection:156°C
- Package: ESOP8

## **Typical Application**

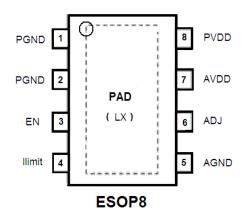
- Portable charger, mobile power.
- Digital cameras, GPS, wireless transceiver
- IPad-like computers, smart phones and portable handheld devices



# **Typical Application Circuit**



# **Pin Configuration**

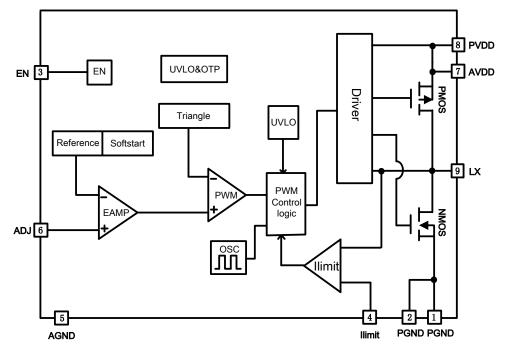


### **Pin information**

Pin Number	Pin Name	Function
1	PGND	Power Ground
2	PGND	Power Ground
3	EN	Power-enable "H" : Power-on (normal operation) "L" : Power-off (standby)
4	llimit	Current limit External transistor
5	AGND	Analog Ground
6	ADJ	Feed Back voltage pin
7	AVDD	IC Analog power supply pin
8	PVDD	IC power supply pin
9	LX	Power switching pin



# **Block Diagram**



# **Absolute Maximum Rang**

PARAMETER	SYMBOL	RATING	UNIT
VDD Pin Voltage	AVDD, PVDD	-0.3~6.0	V
LX Pin Voltage	$V_{LX}$	-0.3~VDD+0.3	V
ADJ Pin Voltage	$V_{ADJ}$	-0.3~VDD+0.3	V
EN Pin Voltage	$V_{\text{EN}}$	-0.3~VDD+0.3	V
Power Dissipation (ESOP8)	Pd	2000	mW
Operating Temperature Range	T <sub>Opr</sub>	-40~+85	°C
Storage Temperature Range	T <sub>stg</sub>	-40~+125	°C

# **External Parts List When Measuring Electrical Characteristics**

Element Name	SYMBOL	VALUE	UNIT
Inductor	L	≤2.2	uH
Input capacitor	CIN	10	uF
Output capacitor	Co1, Co2	22	uF
Output capacitor	Co3	0.1	uF
ADJ Resistance	R1,R2	30K,10K	Ω



# **Electrical Characteristics**

Measuring conditions:  $V_{IN}=V_{EN}=3.3V$ ,  $V_{OUT}=5.0V$ , Ta=25 °C  $\circ$  Unless otherwise specified  $\circ$ 

Parameter	Symbol	Condition	Min	Тур.	Max	Unit
Feedback voltage	V <sub>ADJ</sub>		1.225	1.250	1.275	V
Input voltage	V <sub>IN</sub>		2.3	-	5.5	V
Current consumption 1	I <sub>SS1</sub>	At switching operation, no external components ,AVDD=PVDD=V <sub>E</sub> <sub>N</sub> =3.3V,V <sub>ADJ</sub> =V <sub>ADJ</sub> (S)× 0.95,	-	4	6	mA
Current consumption 2	I <sub>SS2</sub>	At switching stop, no external components, AVDD=PVDD=V <sub>EN</sub> =3.3V V <sub>ADJ</sub> =V <sub>ADJ</sub> (S)+ 0.5V,	-	150	300	μA
Current consumption during shutdown	I <sub>SSS</sub>	AVDD=PVDD= 3.3V, V <sub>EN</sub> =0V, no external components	-	-	1	μA
Oscillation frequency	Fosc		0.8	1.0	1.2	MHz
Max. duty ratio	MAXDUT Y	V <sub>IN</sub> =V <sub>EN</sub> = 0.9V, no load	-	81	-	%
PWM/PFM switching duty ratio	PFMDUT Y	V <sub>IN</sub> =V <sub>EN</sub> = 3.3V,no load	-	18	-	%
High level input voltage	$V_{SH}$	$V_{IN}$ = 2.3V to 5.5 V, EN pin	0.9	-	-	V
Low level input voltage	V <sub>SL</sub>	$V_{IN}$ =2.3V to 5.5 V, EN pin	-	-	0.2	V
ADJ pin input current	I <sub>ADJ</sub>	AVDD= PVDD= V <sub>EN</sub> =2.3 V to 5.5 V, ADJ pin	-0.1	0	0.1	μA
UVLO release voltage	V <sub>UVLO+</sub>		-	-	2.4	V
UVLO hysteresis width	V <sub>UVLOHYS</sub>		-	0.4	-	V
Soft start time	t <sub>ss</sub>	-	-	3	-	mS
Thermal Shutdown Protection	Tsd		-	156	-	°C

Note:

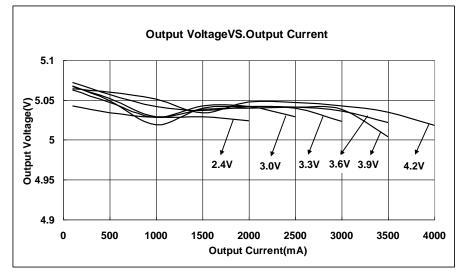
• Set the input voltage as to 2.3 V $\leq$ V<sub>IN</sub> $\leq$ 5.5V for stabilizing the output voltage and oscillation frequency.

•  $V_{ADJ}(S)$  is a setting value for ADJ voltage.

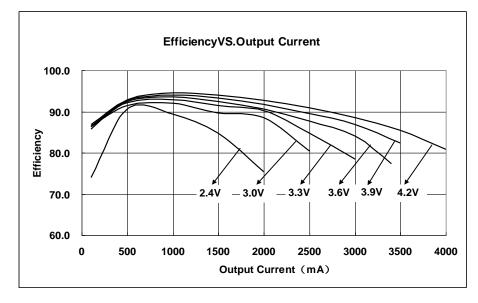


# **Typical Performance Characteristics**

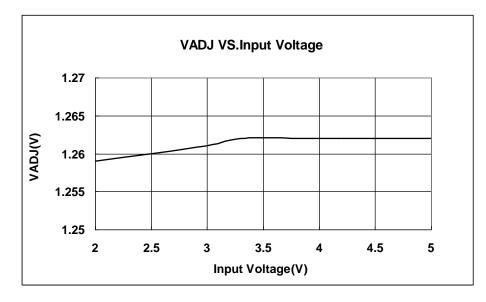
1、Output Voltage VS. Output Current ( $V_{OUT} = 5.0V$ )



2、Efficiency VS. Output Current (V<sub>OUT</sub> =5.0V)

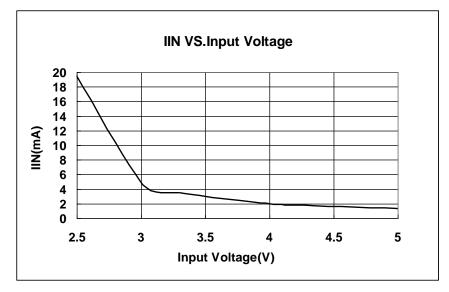


3、V<sub>ADJ</sub> VS. Input Voltage (I<sub>OUT</sub>=10mA)

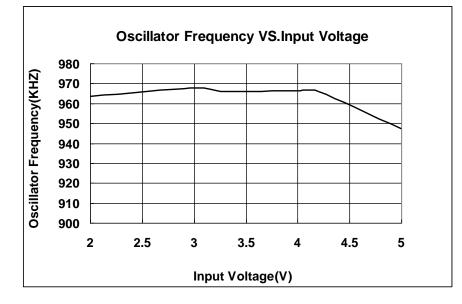




4、IIN VS. Input Voltage (system testing, No load)



5、Oscillator Frequency VS. Input Voltage (VIN=3.3V,IOUT=500mA)





#### **PWM / PFM switching control**

The ME2183 switching regulator controller automatically switches between the pulse width modulation method (PWM) and pulse frequency modulation method (PFM) according to the load current. A low ripple power can be supplied by operating on PWM control for which the pulse width changes from 15% to 85% in the range where the output load current is large. The ME2183 operates on PFM control when the output load current is small and the fixed pulses which have the width of 15% are skipped according to the load current amount. Therefore, the oscillation circuit intermittently oscillates, reducing the self-current consumption. This avoids decreased efficiency when the output load current is small. The point at which PWM control switches to PFM control varies depending on the external element (inductor, diode, etc.), input voltage value, and output voltage value.

#### Soft-start function

The ME2183 has a soft-start circuit. The output voltage ( $V_{OUT}$ ) gradually rises after power-on or startup when the EN pin is set to high, suppressing rush current and overshooting the output voltage. The soft-start time (tss) for the ME2183 is defined as the time from startup until  $V_{OUT}$  reaches 90% of the output set voltage value ( $V_{OUT}(S)$ ). A reference voltage adjustment method is used as the soft-start method and the reference voltage gradually rises from 0 V after soft-start.

#### **UVLO** function

The ME2183 has a UVLO (under voltage lockout) circuit for avoiding IC malfunctions due to power supply voltage drops. The ME2183 stops switching operation upon UVLO detection and retains the external transistor in the off state. After entering the UVLO detection status once, the soft-start function is reset.

Note, however, that the other internal circuits operate normally and that the status differs from the power-off status.

#### **CURRENT LIMIT DESIGNING**

The ME2183 has a cycle-by-cycle current limit to maximum inductor peak current ( $I_{PK}$ ), adjust inductor peak current limit ( $I_{pklimit}$ ) by the Rcs with calculating the value for RCS as

$$\mathsf{R}_{\mathsf{CS}} \approx \frac{5}{I_{\mathsf{pklimit}} \times R_{\mathsf{DSON}}}$$

The  $R_{DSON}$  is the ON-resistance of Nch Power MOS and the value of  $R_{DSON}$  is about 40m $\Omega$  in this product. When an over current condition is detected, the device reduces the output voltage accordingly.

When Output Current (IOUT) increases The inductor peak current (Ipk) increases, as The inductor peak current up to  $I_{pklimit,}$ , the Output Current is the  $I_{OLIMIT}$ 



### L=2.2uH , Co1,Co2=22uF ,CIN=10Uf,VOUT=5V

Table 1. Common R<sub>CS</sub> Resistor Selections

VIN=3.3V				
R <sub>cs</sub>	I <sub>pklimit</sub>			
60K	2.15A			
30K	4.30A			
25K	5.16A			
20K	6.45A			

NOTE: When selecting an  $R_{CS}$  be careful about the influence of temperature at the  $R_{DSON}$  and other devices, select an  $R_{CS}$  inductor such that that  $I_{pklimit}$  does not exceed the allowable current

### External parts selection for DC/DC converter

#### Inductor

The recommended L value of ME2183 is 2.2 $\mu$ H or less for 1.0 MHz products. Note the following when changing the inductance. The inductance (L) has a strong influence on the maximum output current ( $I_{OUT}$ ) and efficiency ( $\eta$ ). The inductor peak current (Ipk) increases when L is decreased, which improves the circuit stability and increases the  $I_{OUT}$  users can obtain. If L is decreased further, the ability of the external transistor to drive the current becomes insufficient, reducing the efficiency and decreasing  $I_{OUT}$ .

The loss due to the lpk of the switching transistor is decreased by increasing L and the efficiency maximizes at a certain L value. If L is increased further, the loss due to the serial resistance of the inductor increases, lowering the efficiency.

Caution: When selecting an inductor, be careful about its allowable current. If a current exceeding the allowable current flows through the inductor, magnetic saturation occurs, substantially lowering the efficiency and destroying ICs due to large current. Therefore, select an inductor such that Ipk does not exceed the allowable current. The following equations express Ipk in the ideal statuses in the discontinuous and continuous modes :

$$Ipk = \sqrt{\frac{2 * Iout * (Vout + VD - VIN)}{f_{osc} * L}} (A) \quad (Discontinuous mode)$$
$$Ipk = \frac{Vout + VD}{VIN} * Iout + \frac{(Vout + VD - VIN) * VIN}{2 * (Vout + VD) * f_{osc} * L} (A) \quad (Continuous mode)$$

F<sub>OSC</sub> is oscillation frequency, VD is the forward voltage of a diode. The reference value is 0.4 V. However, current exceeding the above equation flows because conditions are practically not ideal. Perform sufficient evaluation with actual application.



### 2. Capacitor (CIN, CO1, CO2)

To improve efficiency, an input capacitor (CIN) lowers the power supply impedance and averages the input current. Select CIN according to the impedance of the power supply used. The recommended capacitance is  $10\mu$ F for ME2183. An output capacitor (C<sub>0</sub>), which is used to smooth the output voltage, requires a capacitance larger than that of the step-down type because the current is intermittently supplied from the input to the output side in the step-up type. A 22µF ceramic capacitor is recommended for ME2183. However, a higher capacitance is recommended if the output voltage is high or the load current is large. If the output voltage or load current is low, another 22µF can be used without problems.

Select C<sub>O</sub> after sufficient evaluation with actual application.

A ceramic capacitor can be used for both the input and output.

### 3.Output voltage setting resistors (R1 , R2 )

For ME2183, V<sub>OUT</sub> can be set to any value by using external divider resistors. Connect the divider

resistors between the  $V_{OUT}$  and  $V_{SS}$  pins. Because  $V_{ADJ}$  = 1.25 V typ.,  $V_{OUT}$  can be calculated by using the following

equation : 
$$V_{OUT} = (\frac{R1 + R2}{R2}) \times 1.25 (V)$$

Connect divider resistors R1 and R2 as close to the IC as possible to minimize the effects of noise.

The typical constants based on our evaluation are shown in the next Table:

V <sub>OUT</sub> (S) (V)	VIN (V)	R1 (KΩ)	R2 (KΩ)	L (µH)	Co1,Co2 (μF)
3.3	2.4	16.4	10	2.2	22
5	3.3	30	10	2.2	22

#### 5. Precautions

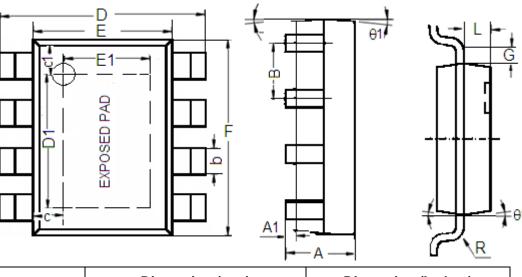
• Mount external capacitors, a diode, and a coil as close as possible to the IC.

- •Characteristics ripple voltage and spike noise occur in IC containing switching regulators. Moreover rush current flows at the time of a power supply injection. Because these largely depend on the inductor, the capacitor and impedance of power supply used, fully check them using an actually mounted model.
- •The 0.1 µF capacitor connected between the VIN and GND pins is a bypass capacitor. It stabilizes the power supply in the IC when application is used with a heavy load, and thus effectively works for stable switching regulator operation. Allocate the bypass capacitor as close to the IC as possible, prioritized over other parts.
- •Although the IC contains a static electricity protection circuit, static electricity or voltage that exceeds the limit of the protection circuit should not be applied.
- •The power dissipation of the IC greatly varies depending on the size and material of the board to be connected. Perform sufficient evaluation using an actual application before designing.



# Package Dimension

Packaging Type: SOP8-PP



Character	Dimensi	on (mm)	Dimension (Inches)			
Character	Min	Max	Min	Max		
A	1.350	1.750	0.053	0.069		
A1	0.1	0.3	0.004	0.012		
В	1.27(	Тур.)	0.05(Typ.)			
b	0.330	0.510	0.013	0.020		
С	0.9(1	Гур.)	0.035(Typ.)			
c1	1.0(1	1.0(Тур.)		0.039(Typ.)		
D	5.8	6.2	0.228	0.244		
D1	3.202	3.402	0.126	0.134		
E	3.800	4.000	0.150	0.157		
E1	2.313	2.513	0.091	0.099		
F	4.7	5.1	0.185	0.201		
L	0.675	0.725	0.027	0.029		
G	0.32(Typ.)		0.013(Typ.)			
R	0.15(Typ.)		0.006(Тур.)			
θ1	<b>7</b> °		7°			
θ	8 <sup>°</sup>		8			



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